^{112}Sn(p,p) IAR   1966Ri06

	Type	Author	History Citation	Literature Cutoff Date
	Full Evaluation	Jean Blachot	NDS 111, 1471 (2010)	1-May-2009

σ(E(p)) at 92°, 125° and 165°, E(p)(C.M.)=6.1-6.9 MeV with semi. L-values from shape of σ(E(p)), 1966Ri06. For resonance parameters, see 1966Ri06.

^{113}Sb Levels

E(level)‡	L	S†	Comments
9280 *40*	0	0	E(p)(C.M.)=6202 *15*. IAS of ^{113}Sn(g.s.) with J$^{\pi}$=1/2^{+}.
9720 *40*	2	440	E(p)(C.M.)=6649 *15*. IAS of ^{113}Sn(410) with J$^{\pi}$=5/2^{+}.
9780 *40*	2	500	E(p)(C.M.)=6710 *15*. IAS of ^{113}Sn(498) with J$^{\pi}$=3/2^{+}.

† E′=E(level)−E(g.s. analog).
‡ From E=res, E(p)(C.M.) + S(p).